

6MBP100RA120

IGBT-IPM R series

1200V / 100A 6 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

- Absolute maximum ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Item	Symbol	Rating		Unit	
		Min.	Max.		
DC bus voltage	V_{bc}	0	900	V	
DC bus voltage (surge)	$V_{bc(surge)}$	0	1000	V	
DC bus voltage (short operating)	V_{sc}	200	800	V	
Collector-Emitter voltage	V_{CES}	0	1200	V	
INV Collector current	DC	I_c	-	100	A
		I_{cP}	-	200	A
	1ms	I_{cP}	-	200	A
		$-I_c$	-	100	A
Collector power dissipation	One transistor	P_c	-	735	W
Junction temperature	T_j	-	150	$^\circ\text{C}$	
Input voltage of power supply for Pre-Driver	V_{cc}^*1	0	20	V	
Input signal voltage	V_{in}^*2	0	V_z	V	
Input signal current	I_{in}	-	1	mA	
Alarm signal voltage	V_{ALM}^*3	0	V_{cc}	V	
Alarm signal current	I_{ALM}^*4	-	15	mA	
Storage temperature	T_{stg}	-40	125	$^\circ\text{C}$	
Operating case temperature	T_{op}	-20	100	$^\circ\text{C}$	
Isolating voltage (Case-Terminal)	V_{iso}^*5	-	AC2.5	kV	
Screw torque	Mounting (M5)	-	3.5^*6	N·m	
	Terminal (M5)	-	3.5^*6	N·m	

*1 Apply V_{cc} between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

*2 Apply V_{in} between terminal No. 2 and 1, 5 and 4, 8 and 7, 13,14,15 and 10.

*3 Apply V_{ALM} between terminal No. 16 and 10.

*4 Apply I_{ALM} to terminal No. 16.

*5 50Hz/60Hz sine wave 1 minute.

*6 Recommendable Value : 2.5 to 3.0 N·m

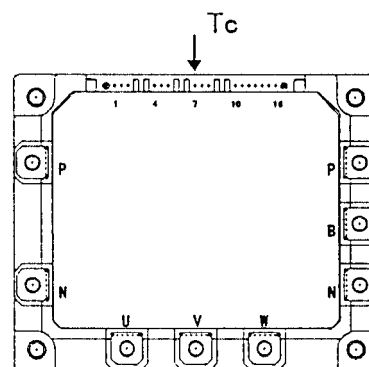


Fig.1 Measurement of case temperature

- Electrical characteristics of power circuit (at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	
INV	Collector current at off signal input	I_{CES}	$V_{CE}=1200\text{V}$ input terminal open	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_c=100\text{A}$	-	-	2.6	V
	Forward voltage of FWD	V_F	$-I_c=100\text{A}$	-	-	3.0	V

● Electrical characteristics of control circuit(at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply current of P-line side Pre-driver(one unit)	I_{ccp}	fsw=0 to 15kHz $T_c=-20$ to 100°C *7	3	-	18	mA
Power supply current of N-line side three Pre-driver	I_{ccn}	fsw=0 to 15kHz $T_c=-20$ to 100°C *7	10	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.70	2.05	2.40	V
Input zener voltage	V_z	$R_{in}=20\text{k ohm}$	-	8.0	-	V
Over heating protection temperature level	T_{COH}	$V_{DC}=0\text{V}$, $I_c=0\text{A}$, Case temperature	110	-	125	$^\circ\text{C}$
Hysteresis	T_{CH}		-	20	-	$^\circ\text{C}$
IGBT chips over heating protection temperature level	T_{jOH}	surface of IGBT chips	150	-	-	$^\circ\text{C}$
Hysteresis	T_{jH}		-	20	-	$^\circ\text{C}$
Collector current protection level	INV I_{oc}	$T_j=125^\circ\text{C}$	150	-	-	A
Over current protection delay time (Fig.2)	t_{DOC}	$T_j=25^\circ\text{C}$ Fig.2	-	10	-	μs
Under voltage protection level	V_{UV}		11.0	-	12.5	V
Hysteresis	V_H		0.2	-	-	V
Alarm signal hold time	t_{ALM}		1.5	2	-	ms
SC protection delay time	t_{SC}	$T_j=25^\circ\text{C}$ Fig.3	-	-	12	μs
Limiting resistor for alarm	R_{ALM}		1425	1500	1575	ohm

*7 Switching frequency of IGBT

● Dynamic characteristics(at $T_c=T_j=125^\circ\text{C}$, $V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	t_{on}	$I_C=100\text{A}$, $V_{DC}=600\text{V}$	0.3	-	-	μs
	t_{off}		-	-	3.6	μs
Switching time (FWD)	t_{rr}	$I_F=100\text{A}$, $V_{DC}=600\text{V}$	-	-	0.4	μs

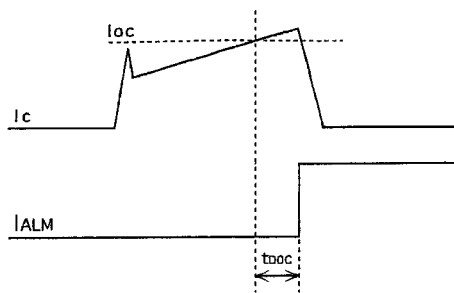


Fig.2 Definition of OC delay time

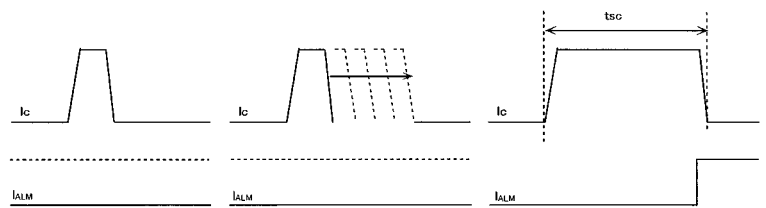


Fig.3 Definition of t_{sc}

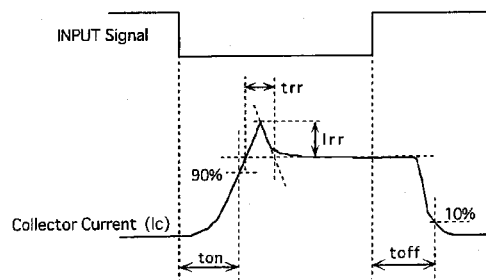


Fig.4 Definition of switching time

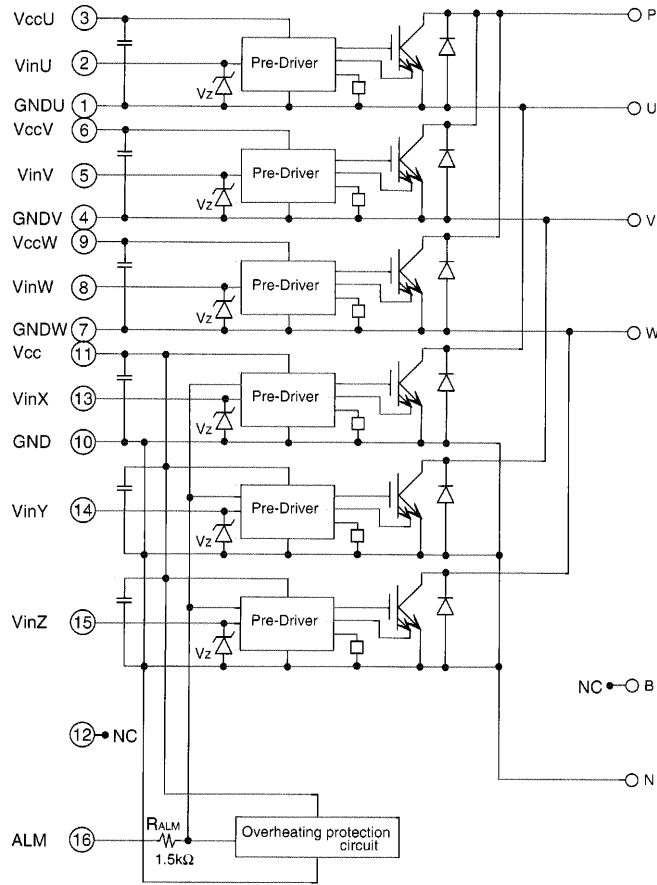
● Thermal characteristics($T_c=25^\circ\text{C}$)

Item	Symbol	Typ.	Max.	Unit
Junction to Case thermal resistance	INV IGBT	-	0.17	$^\circ\text{C/W}$
	FWD	-	0.36	$^\circ\text{C/W}$
Case to fin thermal resistance with compound	$R_{th(c-f)}$	0.05	-	$^\circ\text{C/W}$

● Recommendable value

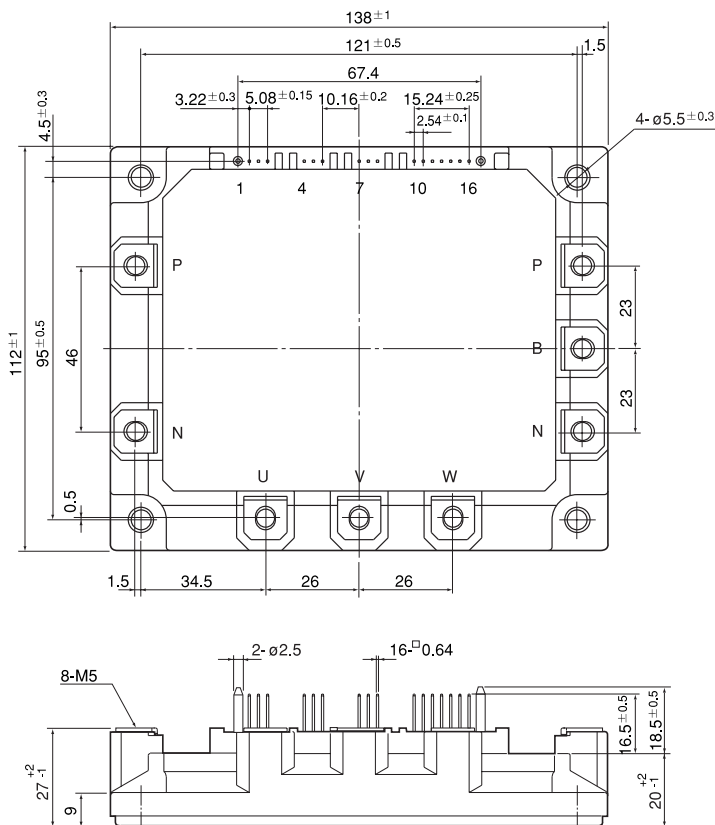
Item	Symbol	Min.	Typ.	Max.	Unit	
DC bus voltage	V_{DC}	200	-	800	V	
Operating power supply voltage range of Pre-driver	V_{cc}	13.5	15	16.5	V	
Switching frequency of IPM	fsw	1	-	20	kHz	
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m
	Terminal (M5)	-	2.5	-	3.0	N·m

Block diagram



- Pre-drivers include following functions
- a) Amplifier for driver
 - b) Short circuit protection
 - c) Undervoltage lockout circuit
 - d) Over current protection
 - e) IGBT chip over heating protection

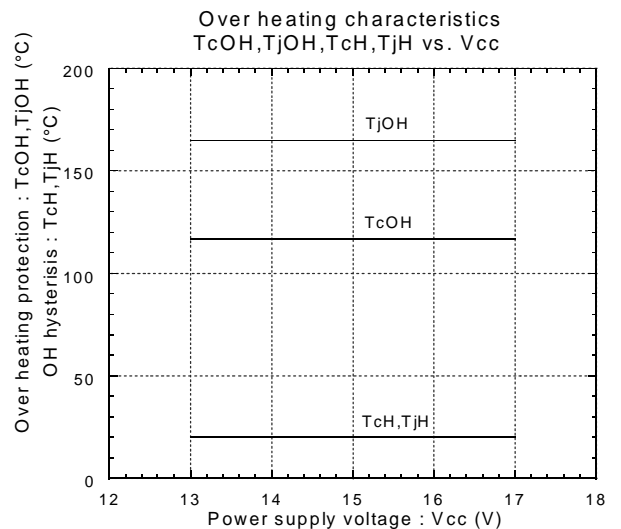
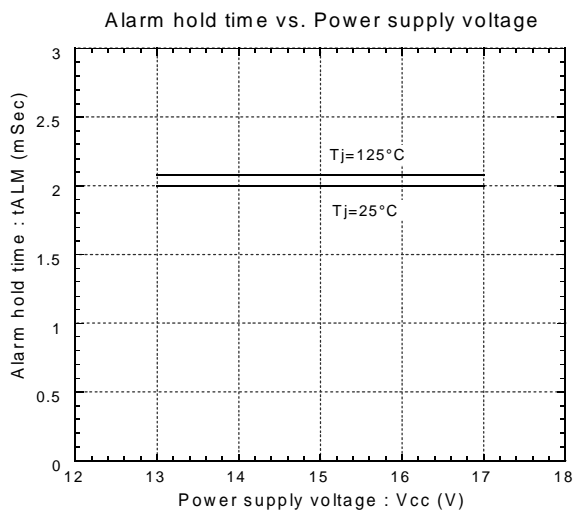
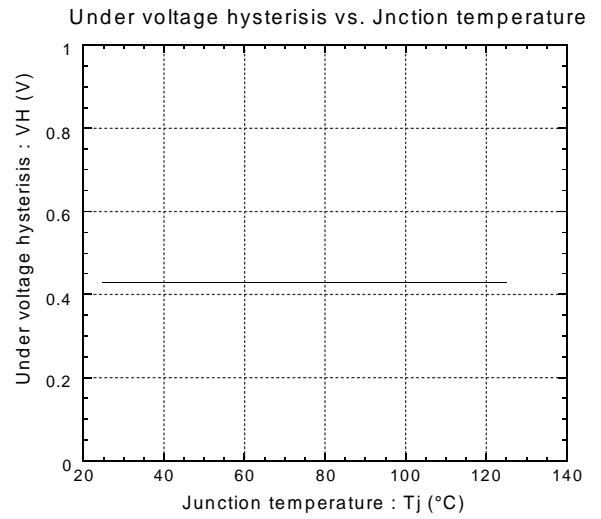
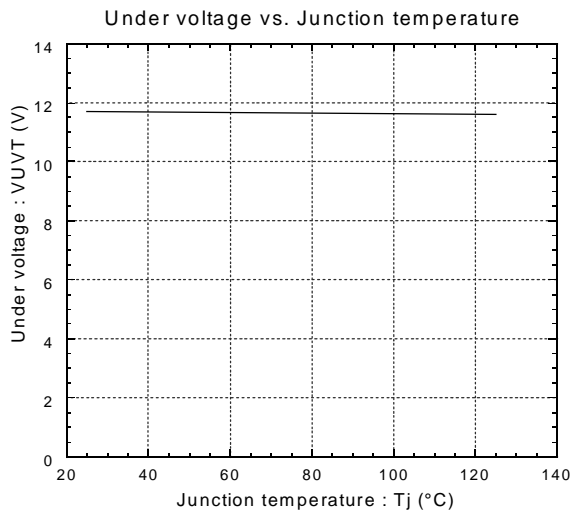
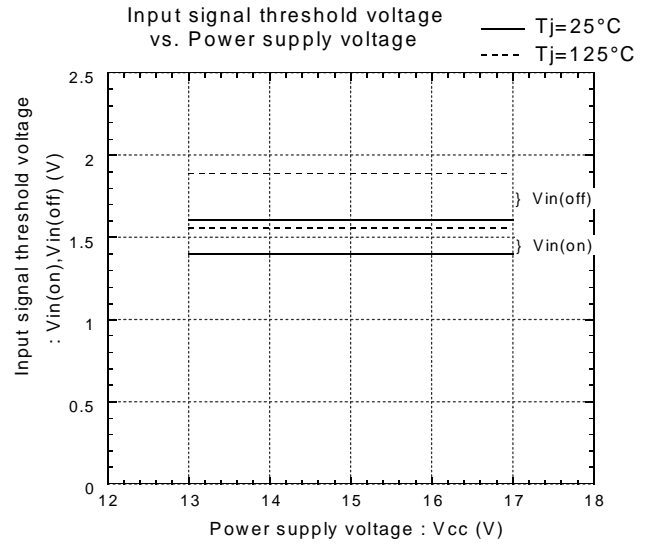
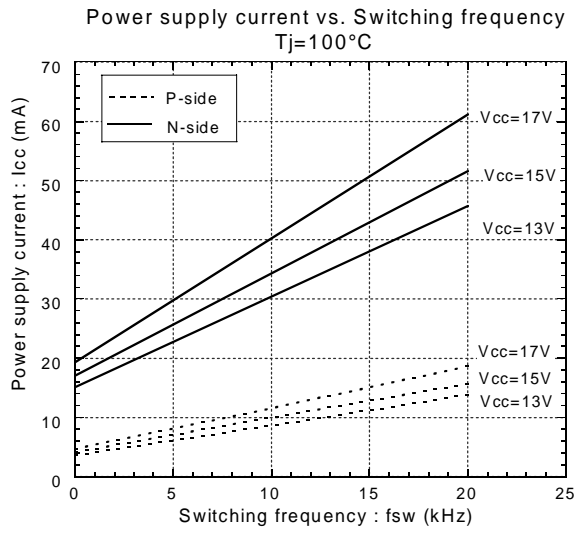
Outline drawings, mm



Mass : 920g

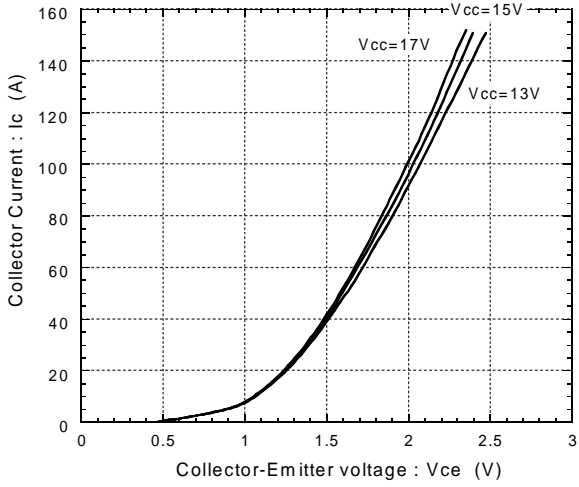
Characteristics (Representative)

Control Circuit

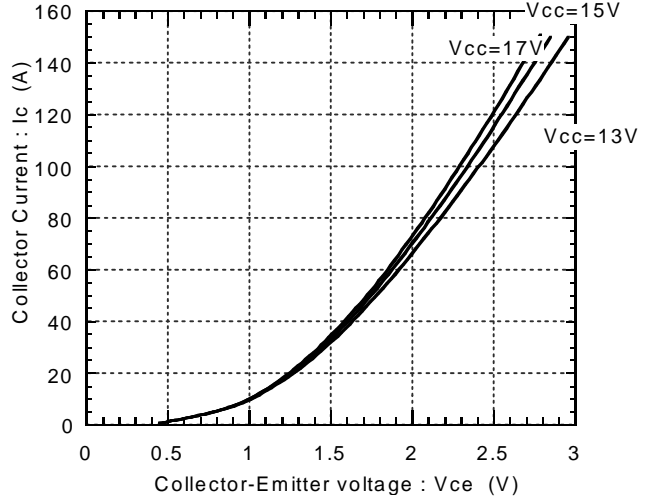


● Inverter

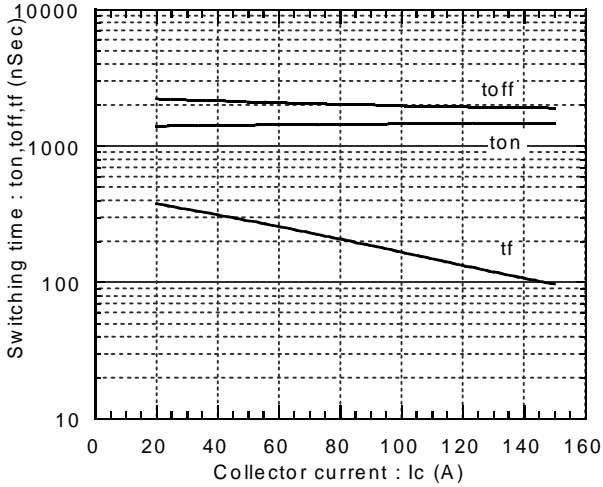
Collector current vs. Collector-Emittor voltage
T_j=25°C



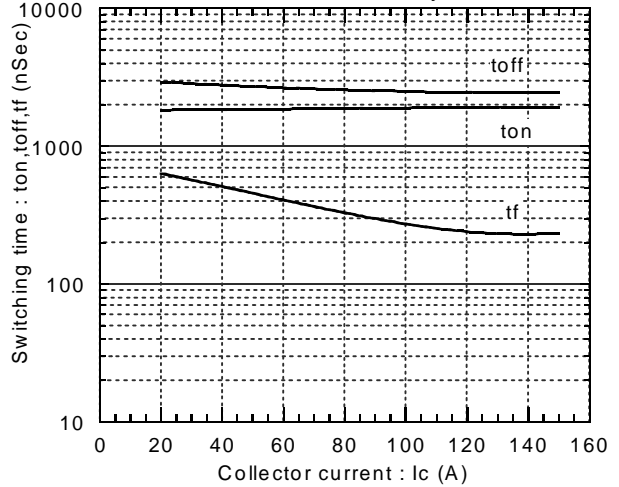
Collector current vs. Collector-Emittor voltage
T_j=125°C



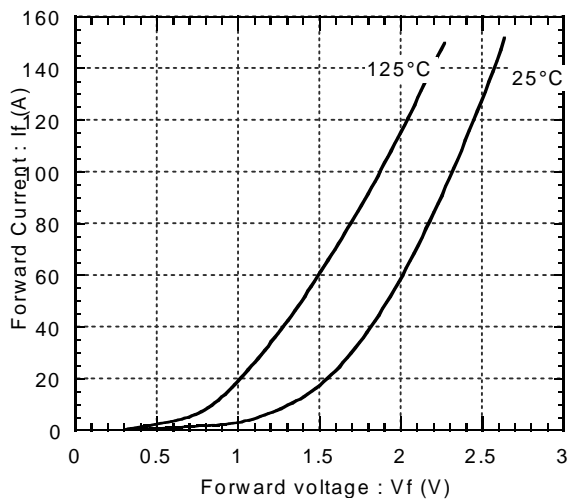
Switching time vs. Collector current
E_{dc}=600V, V_{cc}=15V, T_j=25°C



Switching time vs. Collector current
E_{dc}=600V, V_{cc}=15V, T_j=125°C



Forward current vs. Forward voltage



Reverse recovery characteristics
trr, Irr vs. IF

